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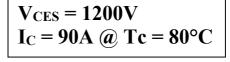


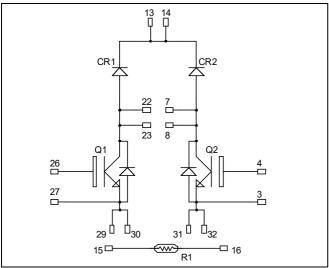


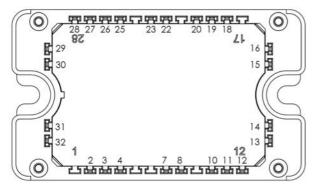




## Dual Boost chopper Trench + Field Stop IGBT4 Power module







All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

#### **Application**

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### **Features**

- Trench + Field Stop IGBT 4
  - Low voltage drop
  - Low leakage current
  - Low switching losses
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a single boost of twice the current capability
- RoHS compliant

## All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

## Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Voltage		1200	V
$I_{\mathrm{C}}$	Continuous Collector Current	$T_c = 25^{\circ}C$	110	
	Continuous Collector Current	$T_c = 80$ °C	90	A
$I_{CM}$	Pulsed Collector Current	$T_c = 25^{\circ}C$	150	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_D$	Power Dissipation	$T_c = 25^{\circ}C$	385	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	150A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

## **Electrical Characteristics** (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V ; V_{CE} = 1200V$				250	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_{C} = 75A$	$T_j = 25^{\circ}C$		1.85	2.25	V
			$T_j = 150$ °C		2.25		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 3 \text{ mA}$		5	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				600	nA

## **Dynamic Characteristics** (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			4.4		
Coes	Output Capacitance				0.29		nF
Cres	Reverse Transfer Capacitance	f = 1MHz			0.24		
$Q_{G}$	Gate charge	$V_{GE}=\pm 15V$ ; $V_{CE}=75A$	$V_{GE} = \pm 15V ; V_{CE} = 600V$ $I_{C} = 75A$		0.57		μС
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switc	hing (25°C)		130		ns
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$			20		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 75A$			300		
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.2\Omega$			45		
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (150°C)		150		
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$			35		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$I_C = 75A$			350		113
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.2\Omega$			80		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$	$T_J = 25$ °C		3.3		mJ
Lon	Turn-on Switching Energy	$V_{Bus} = 600V$ $T_{J} = 150$	$T_J = 150$ °C		8.5		1113
$E_{\rm off}$	Turn-off Switching Energy	$I_C = 75A$	$T_J = 25^{\circ}C$		4.2		mJ
Lom	Turn on Switching Energy	$R_G = 2.2\Omega$	$T_J = 150$ °C		7.2		1113
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V ; V_{Bu}$ $t_p \le 10 \mu s ; T_j = 1$			300		A
$R_{thJC}$	Junction to Case Thermal Resistance					0.39	°C/W

## Chopper diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Typ	Max	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage					1200	V
$I_{RM}$	Reverse Leakage Current	$V_R = 1200V$				100	μΑ
$I_{\mathrm{F}}$	DC Forward Current		$Tc = 80^{\circ}C$		100		A
		$I_{\rm F} = 100 A$			2.4	3	V
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 150A$			2.7		
		$I_F = 100A$	$T_j = 125$ °C		1.8		
+	-	$T_j = 25$ °C			385		ng.
$\iota_{rr}$		$I_F = 100A$ - $V_R = 800V$	$T_j = 125$ °C		480		ns
Qrr	Reverse Recovery Charge	$\frac{V_R - 800V}{\text{di/dt} = 200\text{A/}\mu\text{s}}$	$T_j = 25$ °C		1055		
			$T_j = 125$ °C		5240		nC
$R_{thJC}$	Junction to Case Thermal Resistance					0.55	°C/W



## Thermal and package characteristics

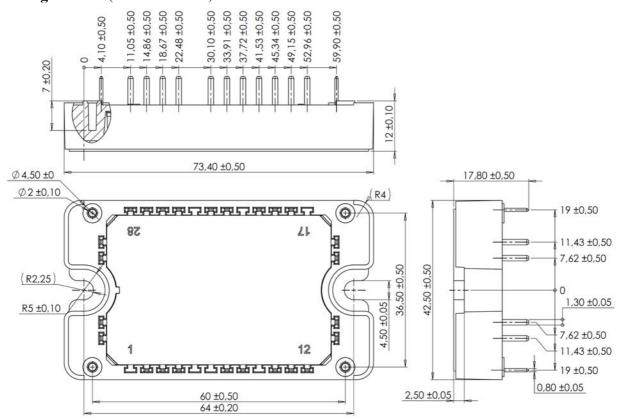
Symbol	Characteristic			Min	Max	Unit	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V	
$T_{\rm J}$	Operating junction temperature range			-40	175		
$T_{JOP}$	Recommended junction temperature under sv	witching condit	ions	-40	T <sub>J</sub> max -25	°C	
$T_{STG}$	Storage Temperature Range			-40	125		
$T_{\rm C}$	Operating Case Temperature			-40	125		
Torque	Mounting torque	To heatsink	M4	2	3	N.m	
Wt	Package Weight				110	g	

## Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T <sub>C</sub> =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_T: \text{ Thermistor value at T}$$

## Package outline (dimensions in mm)

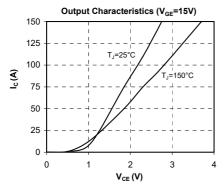


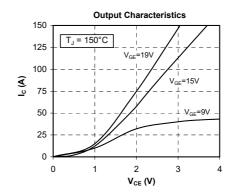
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

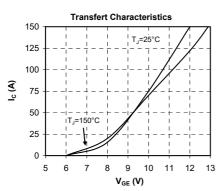
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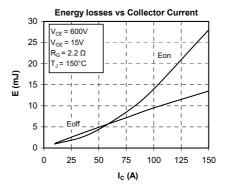


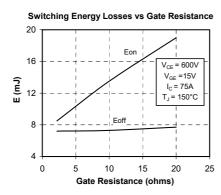
## **Typical Performance Curve**

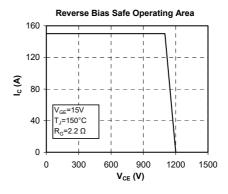


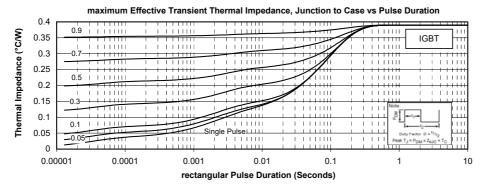




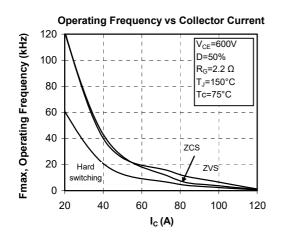


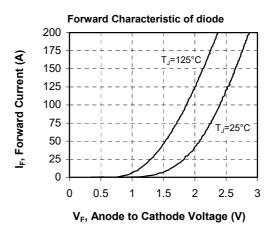


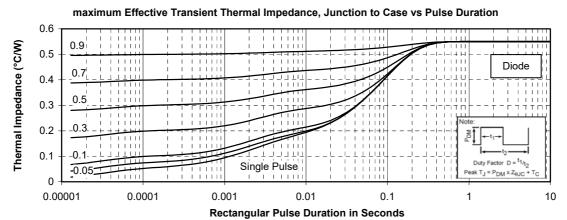












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